

Electronic Analog of Electro-Optic Modulator

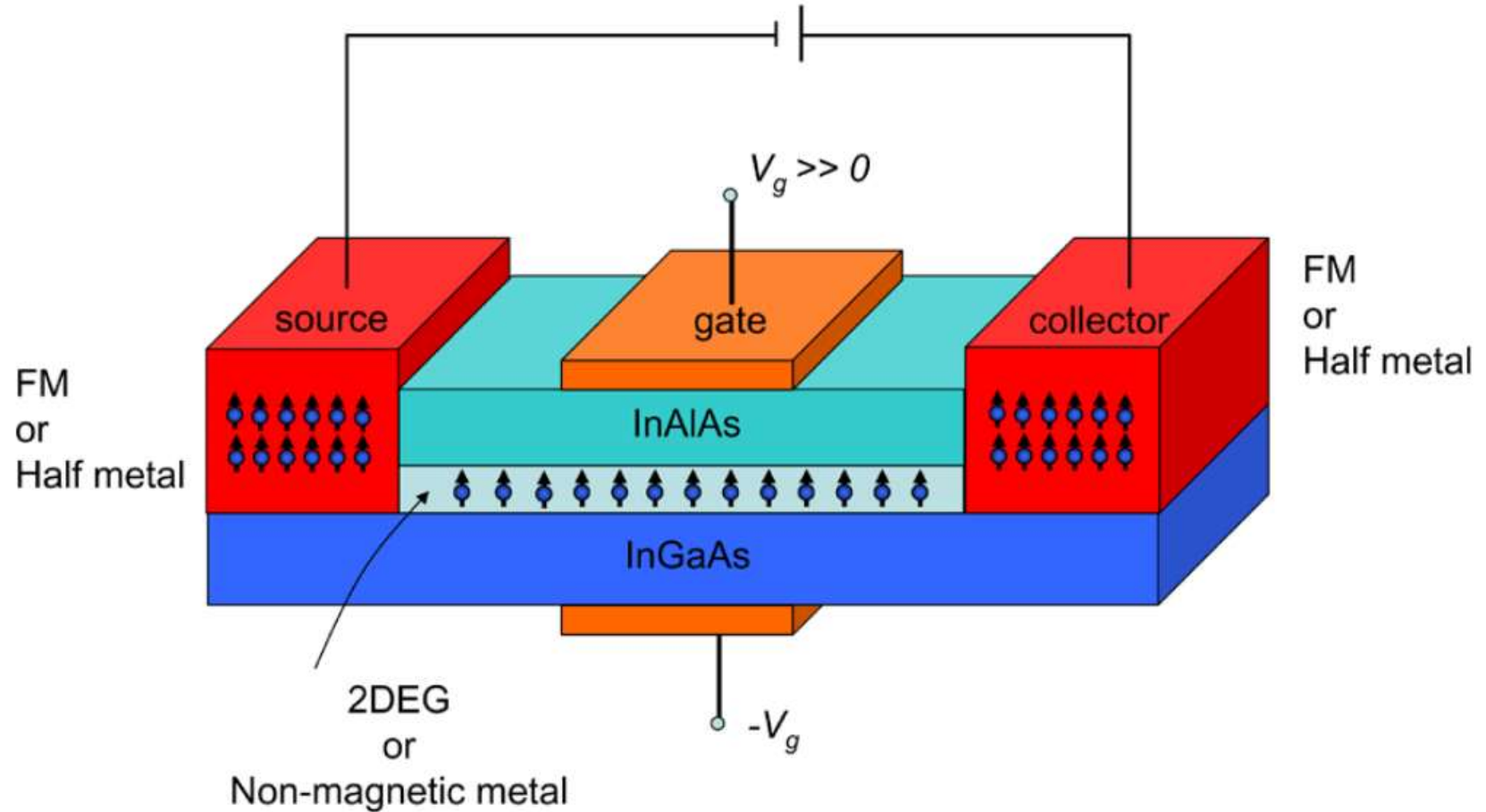
Minhyeong Lee



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Motivation



Appl. Phys. Lett, Supriyo Datta and Biswajit Das 56, 665 (1990)

1. Electro-optic modulator

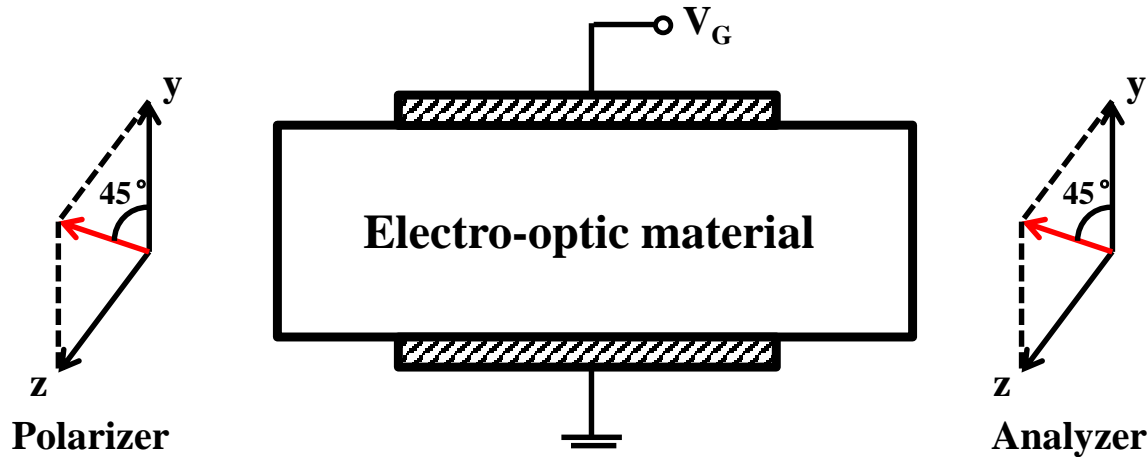


Electronic analog of the electro-optic modulator

- Electro-optic modulator**

$$\begin{pmatrix} 1 \\ 1 \end{pmatrix} = \begin{pmatrix} 1 \\ 0 \end{pmatrix} + \begin{pmatrix} 0 \\ 1 \end{pmatrix}$$

(45° pol.) (z pol.) (y pol.)



- $\begin{pmatrix} e^{ik_1L} \\ e^{ik_2L} \end{pmatrix}$: The light emerging from the electro-optic material
- $\begin{pmatrix} 1 \\ 1 \end{pmatrix}$: The analyzer at the output lets the component $\begin{pmatrix} 1 \\ 1 \end{pmatrix}$ along to pass through
- The output power $P_0 \propto \left| \begin{pmatrix} 1 & 1 \end{pmatrix} \begin{pmatrix} e^{ik_1L} \\ e^{ik_2L} \end{pmatrix} \right|^2$

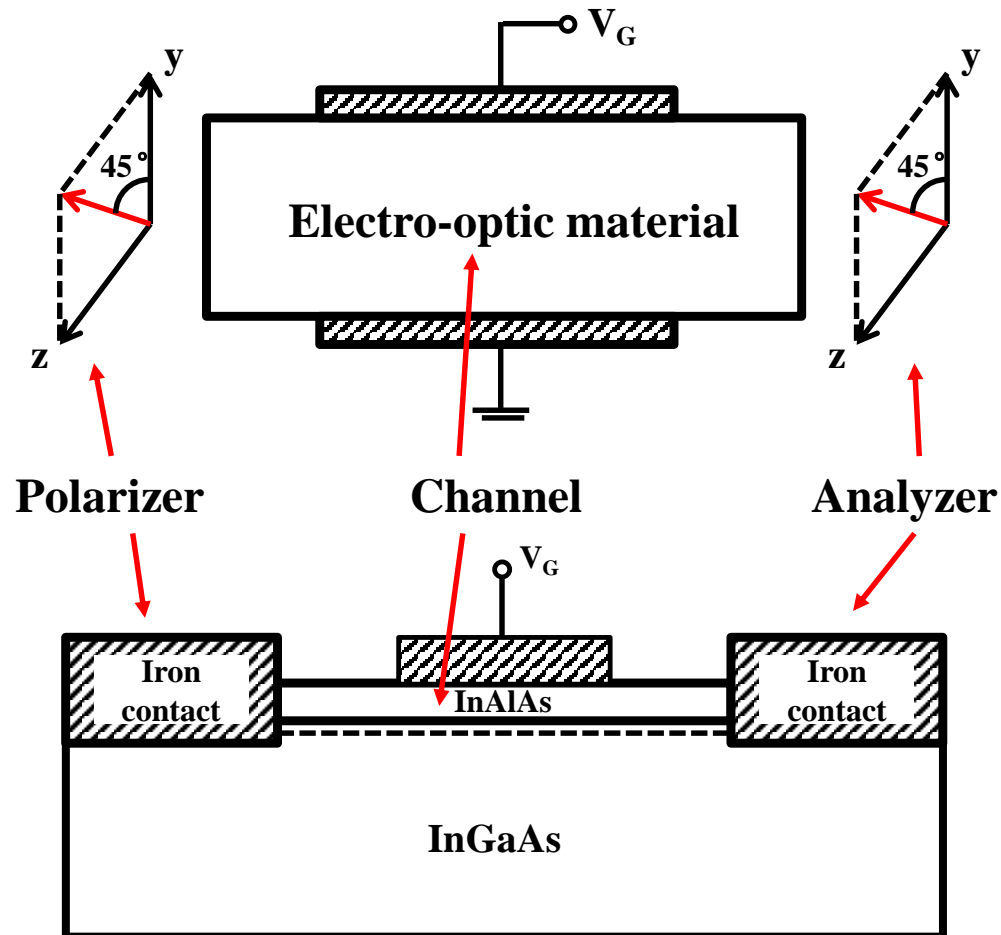
- **Electro-optic modulator**

- $P_0 \propto \left| (1 \ 1) \begin{pmatrix} e^{ik_1 L} \\ e^{ik_2 L} \end{pmatrix} \right|^2$
- $$\begin{aligned} \left| (1 \ 1) \begin{pmatrix} e^{ik_1 L} \\ e^{ik_2 L} \end{pmatrix} \right|^2 &= |e^{ik_1 L} + e^{ik_2 L}|^2 \\ &= (e^{ik_1 L} + e^{ik_2 L})(e^{-ik_1 L} + e^{-ik_2 L}) \\ &= 2 + e^{i(k_2 - k_1)L} + e^{i(k_1 - k_2)L} \\ &= 2 + \cos\{(k_2 - k_1)L\} + \cos\{(k_1 - k_2)L\} \\ &= 2 + 2\cos\{(k_1 - k_2)L\} \\ &= 4 \left(\frac{1 + \cos\{(k_1 - k_2)L\}}{2} \right) = 4 \cos^2 \left\{ \frac{(k_1 - k_2)L}{2} \right\} \end{aligned}$$
- $P_0 \propto 4 \cos^2 \left\{ \frac{(k_1 - k_2)L}{2} \right\}, \quad \{\Delta\theta = (k_1 - k_2)L\}$
- The light output is modulated with a gate voltage that controls the differential phase shift $\Delta\theta = (k_1 - k_2)L$

2. Analogous device based on electron waves

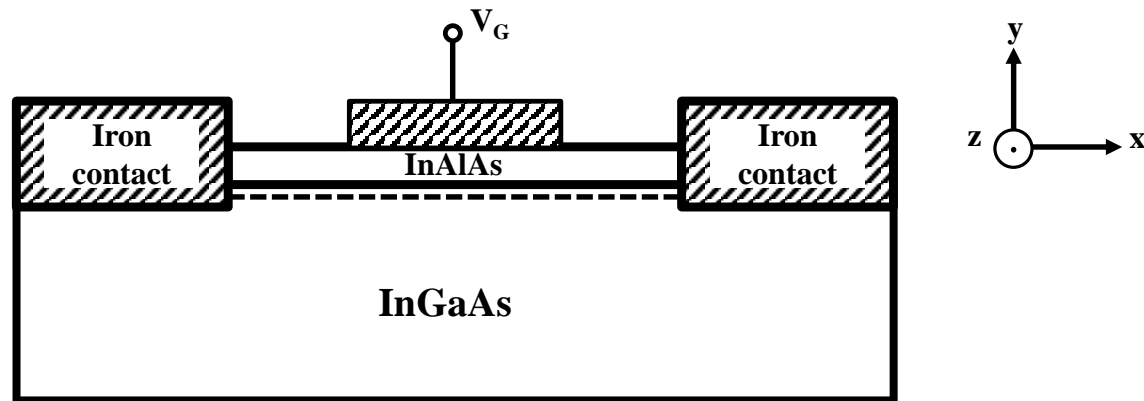
Electronic analog of the electro-optic modulator

- Analogous device based on electron waves



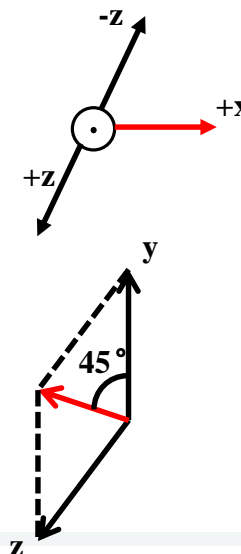
Electronic analog of the electro-optic modulator

- Analogous device based on electron waves



- Detect electrons $\begin{pmatrix} 1 \\ 1 \end{pmatrix} = \begin{pmatrix} 1 \\ 0 \end{pmatrix} + \begin{pmatrix} 0 \\ 1 \end{pmatrix}$
 (+x pol.) (+z pol.) (-z pol.)

- Detect electrons $\begin{pmatrix} 1 \\ 1 \end{pmatrix} = \begin{pmatrix} 1 \\ 0 \end{pmatrix} + \begin{pmatrix} 0 \\ 1 \end{pmatrix}$
 (45° pol.) (z pol.) (y pol.)



• Analogous device based on electron waves

- Consider an electron traveling in the x direction with $k_z = 0$, $k_x \neq 0$ (we assume that the electron forms a 2DEG in the x-z plane)

- Rashba term $H_R = \eta(\sigma_z k_x - \sigma_x k_z) = \eta \sigma_z k_x$

- $E(+z \text{ pol.}) = \frac{\hbar^2 k_{x1}^2}{2m^*} - \eta k_{x1}$

- $E(-z \text{ pol.}) = \frac{\hbar^2 k_{x2}^2}{2m^*} + \eta k_{x2}$

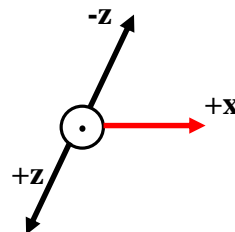
- $|E(+z \text{ pol.})| = |E(-z \text{ pol.})|$

$$\frac{\hbar^2 k_{x1}^2}{2m^*} - \eta k_{x1} = \frac{\hbar^2 k_{x2}^2}{2m^*} + \eta k_{x2}$$

$$\frac{\hbar^2 k_{x1}^2}{2m^*} - \frac{\hbar^2 k_{x2}^2}{2m^*} = \eta k_{x1} + \eta k_{x2}$$

$$k_{x1} - k_{x2} = \frac{2m^* \eta}{\hbar^2}$$

- $\Delta\theta = (k_{x1} - k_{x2})L = \frac{2m^* \eta L}{\hbar^2} \propto \eta$ (spin-orbit coefficient)



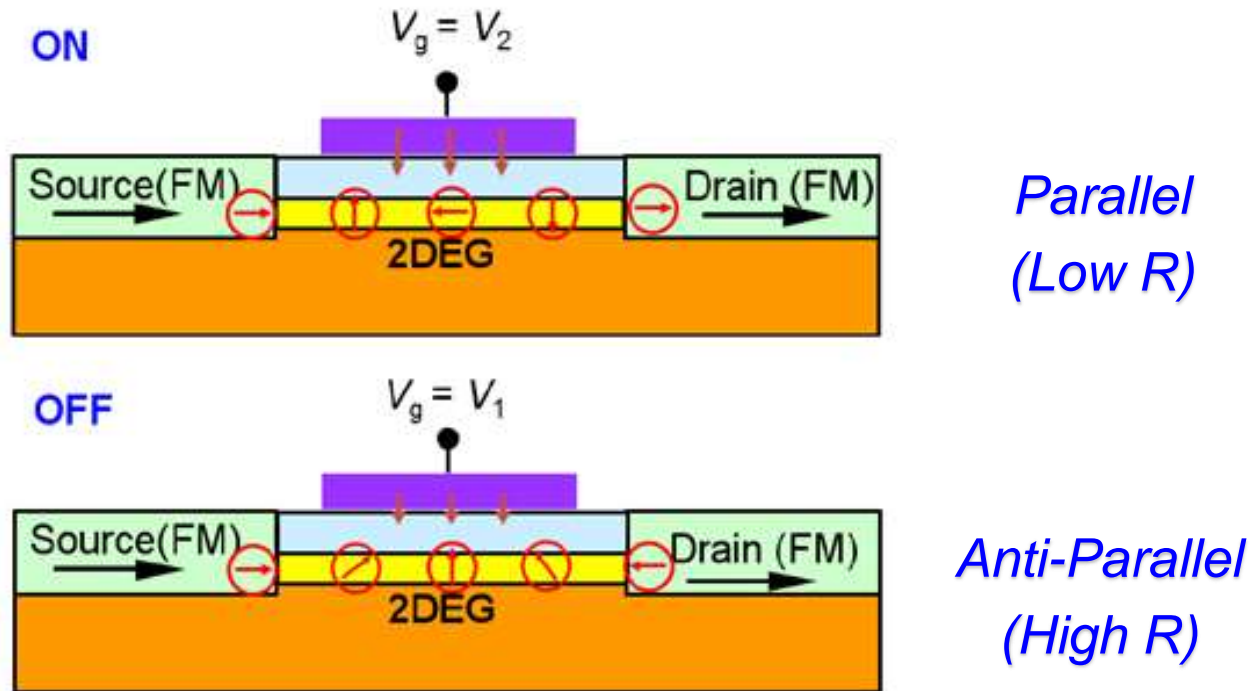
- **Analogous device based on electron waves**

- $\Delta\theta = (k_{x1} - k_{x2})L = \frac{2m^*\eta L}{\hbar^2} \propto \eta$ (spin-orbit coefficient)
 λ = mean free path.
- Is η large enough that a phase difference of π can be introduced within a mean free path?
- $L(\theta = \pi) = \frac{\Delta\theta \hbar^2}{2m^*\eta} = \frac{\pi(1.05 \cdot 10^{-34} J \cdot s)^2}{2 \cdot 0.046 \cdot 9.1 \cdot 10^{-31} kg \cdot 3.9 \cdot 10^{-12} eV \cdot m} = 0.67 \mu m < \lambda$
- η is proportional to the expectation value of the electric field at the hetero-structure interface, and, in principle, can be controlled by the application of a gate voltage
- $\Delta\theta = (k_{x1} - k_{x2})L = \frac{2m^*\eta L}{\hbar^2}$

3. Summary



- **Summary**



- Challenges

- 1) Source & drain : how well the spin **polarizer** and **analyzer** can be implemented.
- 2) Channel : what extent η can be controlled with a **gate voltage**.

Thank you !

